

# IR2C36 7-Unit 500mA Transistor Array

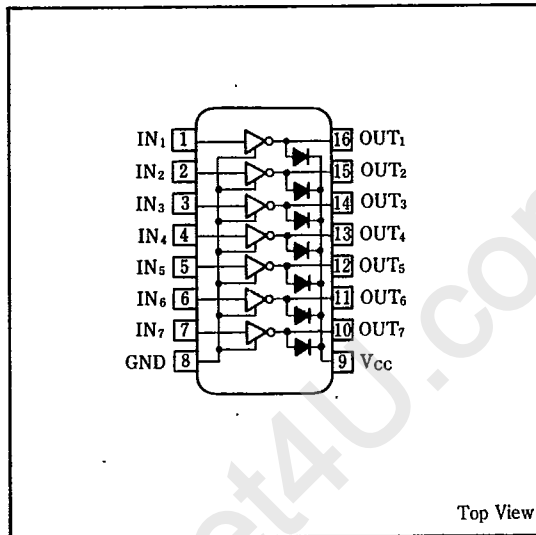
## ■ Description

The IR2C36 is a 7-circuit driver IC. Incorporating an overshoot preventive clamp diode for output, this transistor array can directly drive an inductive load.

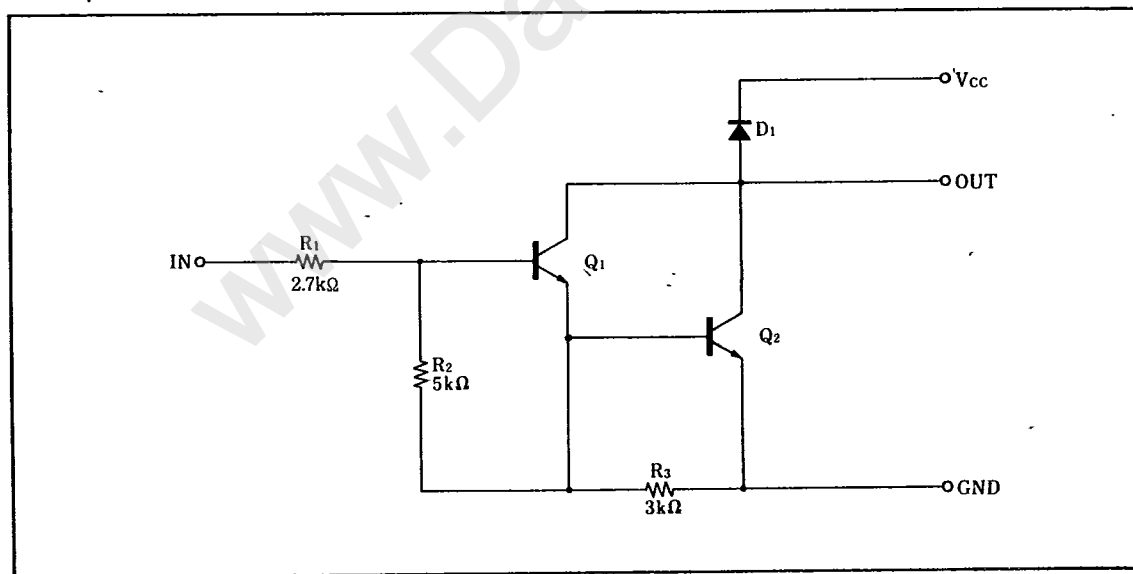
## ■ Features

1. High output current  $I_{OUT} = 500\text{mA}$  (MAX.)
2. High output breakdown voltage  $BV_{CEO} = 50\text{V}$  (MAX.)
3. Built-in output clamp diode
4. Allows for direct drive with TTL or CMOS IC output
5. Darlington structure
6. 16-pin dual-in-line package

## ■ Pin Connections



## ■ Equivalent Circuit



SHARP

### Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	$V_{CC}$		50	V
Output breakdown voltage	$BV_{CEO}$		50	V
Output current	$I_{OUT}$	each circuit, $T_a=25^\circ\text{C}$	500	mA
Input voltage	$V_{IN}$		30	V
Clamp diode reverse breakdown voltage	$BV_R$		50	V
Clamp diode forward current	$I_{f\text{ MAX}}$		40	mA
Clamp diode surge current	$I_{surge}$		400	mA
Load inductance	$L_z$		100	mH
Power dissipation	$P_D$	$T_a \leq 25^\circ\text{C}$	1.47	W
$P_D$ derating ratio	$\Delta P_D/^\circ\text{C}$	$T_a > 25^\circ\text{C}$	11.76	mW/ $^\circ\text{C}$
Operating temperature	$T_{opr}$		-25 ~ +75	$^\circ\text{C}$
Storage temperature	$T_{stg}$		-55 ~ +150	$^\circ\text{C}$

### Recommended Operating Conditions

(Ta=25°C)

Parameter	Symbol	Condition	Rating	Unit
Maximum output voltage	$V_{CEO}$		50	V
Operating temperature	$T_{opr}$		-20 ~ +75	$^\circ\text{C}$
Output current	$I_{OUT}$	at 15% duty	0 ~ 400	mA
		at 50% duty	0 ~ 200	mA

### Electrical Characteristics

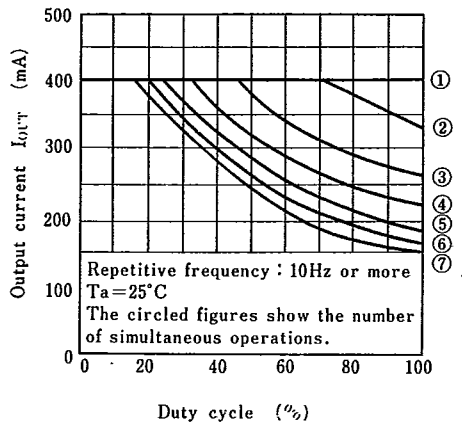
Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	$V_{CC}$				50	V
Input current at ON	$I_{IN\ ON}$	$V_{IN}=3.85\text{V}, I_{OUT}=0$		0.95	1.8	mA
		$V_{IN}=25\text{V}, I_{OUT}=0$		9	18	mA
Output voltage at ON	$V_{OUT\ ON}$	$V_{IN}=3.85\text{V}, I_{OUT}=400\text{mA}$			2.2	V
		$V_{IN}=3.85\text{V}, I_{OUT}=200\text{mA}$			1.4	V
Output current at OFF	$I_{OUT\ OFF}$	$V_{IN}=0\text{V}, V_{OUT}=50\text{V}$			100	$\mu\text{A}$
Diode forward voltage	$V_F$	$I_F=400\text{mA}$			22	V
Diode leakage current	$I_R$	$V_R=50\text{V}$			100	$\mu\text{A}$
Input "High" voltage	$V_{IN\ ON}$	$I_{OUT}=400\text{mA}$	3.85			V
		$I_{OUT}=100\text{mA}$	3.4			V
Input "Low" voltage	$V_{IN\ LOW}$				0.6	V
DC current amplification	$h_{FE}$	$V_{CE}=4\text{V}, I_{OUT}=350\text{mA}, T_a=25^\circ\text{C}$	1000			

Duty cycle: 15% or less, repetitive frequency: 10Hz or more

Electrical Characteristic Curves

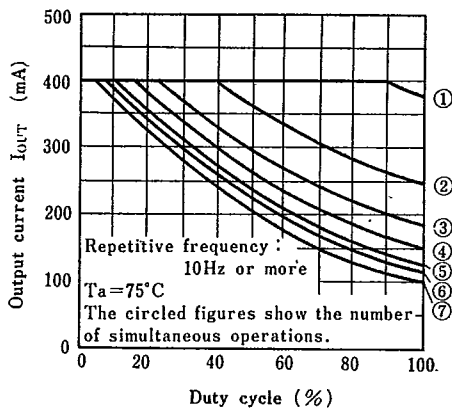
Output current—Duty cycle

Characteristics (1)



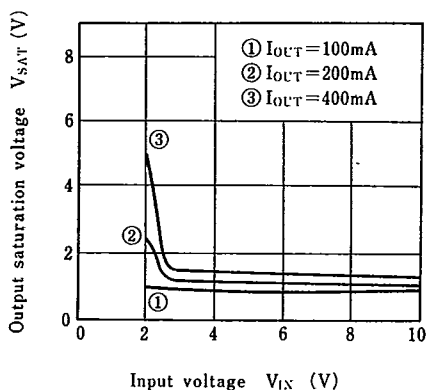
Output current—Duty cycle

Characteristics (2)

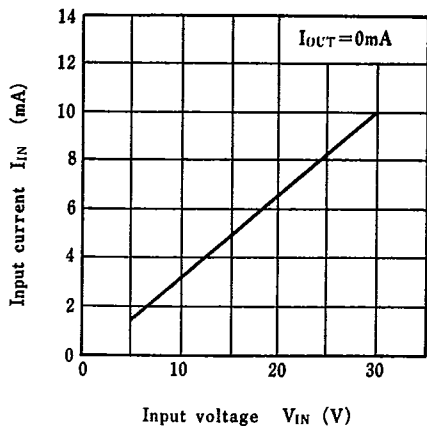


Output saturation voltage (VSAT)—Input voltage

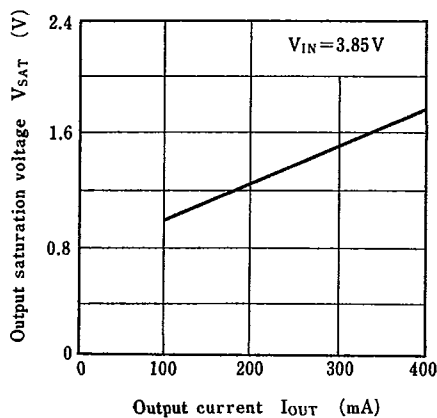
Characteristics (VIN)



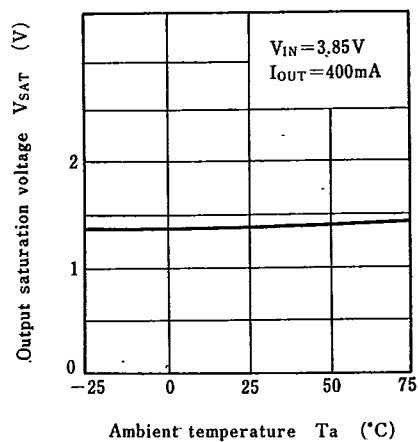
Input current—Input voltage Characteristics



Output saturation voltage—Output current Characteristics



Output saturation voltage  
— Ambient temperature Characteristics



Input current— Ambient temperature  
Characteristics

